# Product Preview SWITCHMODE Schottky Power Rectifier

The SWITCHMODE Power Rectifier employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-artgeometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for use as rectifiers in very low-voltage, high-frequency switching power supplies, free wheeling diodes and polarity protection diodes.

## Features

- Highly Stable Oxide Passivated Junction
- Very Low Forward Voltage Drop
- Matched Dual Die Construction
- High Junction Temperature Capability
- High dv/dt Capability
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guardring for Stress Protection
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Electrically Isolated. No Isolation Hardware Required.
- This is a Pb–Free Device

## **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

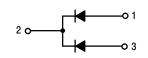
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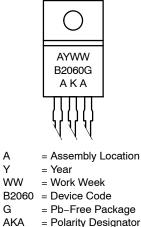
http://onsemi.com

# SCHOTTKY BARRIER RECTIFIER 20 AMPERES, 60 VOLTS









## **ORDERING INFORMATION**

Device	Package	Shipping
MBRJ2060CTG	TO-220 (Pb-Free)	50 Units/Rail

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## MAXIMUM RATINGS (Per Leg)

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	60	V
Average Rectified Forward Current (Rated $V_R$ ), $T_C$ = 133°C	Total Device	I <sub>F(AV)</sub>	10 20	A
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz), T <sub>C</sub> = 133°C		I <sub>FRM</sub>	20	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I <sub>FSM</sub>	150	А
Peak Repetitive Reverse Surge Current (2.0 µs, 1.0 kHz)		I <sub>RRM</sub>	0.5	А
Operating Junction and Storage Temperature Range (Note 1)		T <sub>J</sub> , T <sub>stg</sub>	– 65 to +175	°C
Voltage Rate of Change (Rated V <sub>R</sub> )		dv/dt	10000	V/µs
RMS Isolation Voltage (t = 0.3 second, R.H. $\leq$ 30%, T_A = 25°C) (Note 2)	Per Figure 4	V <sub>iso1</sub>	4500	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## THERMAL CHARACTERISTICS (Per Leg)

Rating		Symbol	Value	Unit
Maximum Thermal Resistance	Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	4.0 105	°C/W
Lead Temperature for Soldering Purposes: 1/8 in from Case for 5 Seconds		ΤL	260	°C

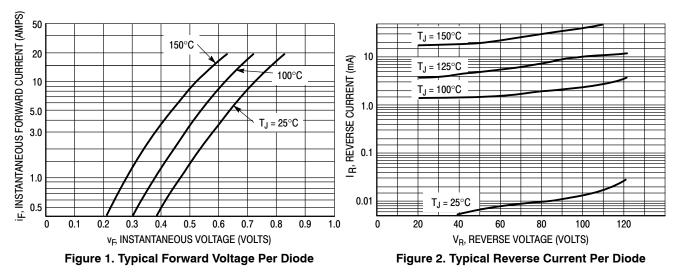
#### ELECTRICAL CHARACTERISTICS (Per Leg)

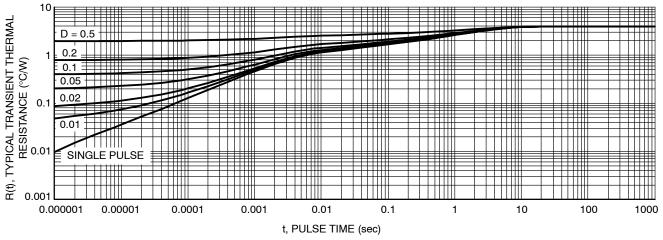
Characteristic	Symbol	Max	Unit
$\label{eq:maximum} \begin{array}{l} \mbox{Maximum Instantaneous Forward Voltage (Note 3)} \\ (i_F = 10 \mbox{ Amp, } T_C = 25^\circ C) \\ (i_F = 10 \mbox{ Amp, } T_C = 125^\circ C) \\ (i_F = 20 \mbox{ Amp, } T_C = 25^\circ C) \\ (i_F = 20 \mbox{ Amp, } T_C = 125^\circ C) \end{array}$	VF	0.85 0.75 0.95 0.85	V
Maximum Instantaneous Reverse Current (Note 3) (Rated DC Voltage, $T_C = 25^{\circ}C$ ) (Rated DC Voltage, $T_C = 125^{\circ}C$ )	i <sub>R</sub>	0.15 150	mA

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

2. Proper strike and creepage distance must be provided.

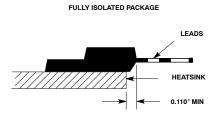
3. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%





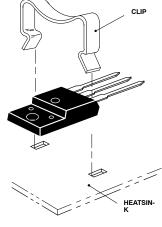


# **TEST CONDITION FOR ISOLATION TEST\***





\*Measurement made between leads and heatsink with all leads shorted together.



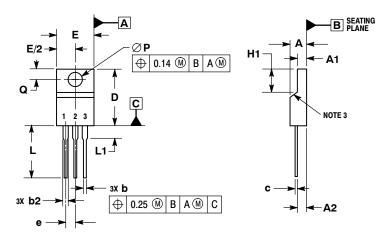
# **MOUNTING INFORMATION**

**Clip-Mounted** 

Figure 5. Typical Mounting Technique

#### PACKAGE DIMENSIONS

#### TO-220 FULLPACK, 3-LEAD CASE 221AH ISSUE C



NOTES

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.

3. CONTOUR UNCONTROLLED IN THIS AREA. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH

AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY. DIMENSION b2 DOES NOT INCLUDE DAMBAR

5. PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

	MILLIMETERS			
DIM	MIN	MAX		
Α	4.30	4.70		
A1	2.50	2.90		
A2	2.50	2.70		
b	0.54	0.84		
b2	1.10	1.40		
C	0.49	0.79		
D	14.70	15.30		
Е	9.70	10.30		
е	2.54	2.54 BSC		
H1	6.70	7.10		
L	12.70	14.73		
L1		2.80		
Ρ	3.00	3.40		
Q	2.80	3.20		
	A A1 A2 b b2 c D E e H1 L1 P	DIM MIN   A 4.30   A1 2.50   b 0.54   b2 1.10   c 0.49   D 14.70   E 9.70   e 2.54   H1 6.70   L 12.70   L1    P 3.00		

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